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### THE SYNTHESIS, CHARACTERIZATION, AND UPCONVERTING PROPERTIES OF ERBIUM DOPED; YTTERBIUM, ERBIUM CO-DOPED YTTRIUM OXYSULFIDE PHOSPHORS UNDER 808, 980, AND 1560 nm EXCITATION

A thesis submitted in partial fulfillment of the requirements for the degree, Master of Chemistry at Virginia Commonwealth University.

by

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> Virginia Commonwealth University Richmond, Virginia May 2011



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### List of Abbreviations

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a.u	Arbitrary Units
cps	Counts Per Second (Photons)
°C	Celsius (degrees)
Em	Emission
ESA	Excited State Absorption
ET	Energy Transfer
GSA	Ground State Absorption
h	Hours
Int.	Intensity
IR	Infrared
kV	Kilovolt
kW	Kilowatt
μW	Microwatt
mA	Microamp
mW	Milliwatt
mol %	
NIR	Near Infrared



nm	Nanometer
QD	Quantum Dot Semiconductor
RE	Rare Earth
SEM	Scanning Electron Microscope
TEM	Transmission Electron Microscopy
UC	Upconversion or Upconverting
UV	Ultraviolet
VIS	Visible
Wt. %	Weight Percent
XRD	X – Ray Diffraction



#### Abstract

Bulk yttrium oxysulfide phosphors were prepared using the polysulfide flux method. The morphology and structure was characterized using transmission electron microscopy and x-ray powdered diffraction. Visible emissions occurring near 530 and 550 nm and 660 - 670 nm consistent with the  ${}^{2}H_{11/2}$ ,  ${}^{4}S_{3/2} \rightarrow {}^{4}I_{15/2}$  and  ${}^{4}F_{9/2} \rightarrow {}^{4}I_{15/2}$ transitions, respectively, were observed under 808, 980, and 1560 nm excitation. The upconverting mechanisms excited at 808, 980, and 1560 nm have been investigated in detail. The power dependent behavior of the upconverted emission intensities for singly doped erbium phosphors excited at 808 and 980 nm indicated a two-photon excitation process. Likewise, the ytterbium and erbium co-doped phosphors excited at 980 nm also indicated a two-photon excitation process. Doping with 10% erbium showed the most intense emissions under 808 and 1560 nm excitation. Yttrium oxysulfide co-doped with 15% ytterbium and 3% erbium showed the most intense emissions under 980 nm excitation. Upon 1560 nm excitation, the intensity of the red emission band was significantly enhanced by co-doping erbium with ytterbium. Concentration quenching became apparent when either the concentration of erbium or ytterbium reached 20%.



# **1. Introduction**



1

High energy ultraviolet (UV) radiation is typically used as the excitation source for the majority of visibly luminescent compounds. The emission produced (usually in the visible region of the electromagnetic spectrum) after the absorption of a single UV photon is a process known as fluorescence. Well known fluorescent compounds such as organic dyes, quantum dot semiconductors (QDs), and downconverters have been well studied for use in a variety of applications. However, for applications involving remote sensing, it is disadvantageous to use UV excited fluorescent compounds mainly due to autofluorescence of background objects caused by the excitation source. Organic dyes are not only susceptible to photobleaching (degradation of photostability) but also require certain pH conditions in order to maintain stability and function properly. More robust than organic dyes, QDs are considered unsafe for practical use in biological and environmental applications due to the elements from which they are made from cadium  $(Cd^{2+})$ , lead  $(Pb^{2+})$ , and selenium  $(Se^{2+})$ . The doping of rare earths (RE) more specifically europium ( $Eu^{3+}$ ) and terbium ( $Tb^{3+}$ ) into host crystalline structures where VIS emissions caused by the absorption of a single UV photon is referred to as downconversion. Downconverters have much better spectral characteristics than organic dyes and QDs which include narrow line emission bands, large Stokes' shifts, and longer excited state lifetimes.<sup>[1], [2]</sup> Nonetheless, highly selective optical reporters using organic dyes, quantum dot semiconductors, and downconverters have been demonstrated successfully leading to the development of new materials and ideas. The use of upconverting phosphors as optical probes is advantageous for remote sensing applications since the



excitation source is in the IR region eliminating the possibility of autofluorescence and need for time-resolved detection.

Upconversion (UC) differs from downconversion in that it is a process that converts multiple near-infrared (NIR) low energy photons into a higher energy UV or VIS photon by either step-wise excited state absorption (ESA) or energy transfer (ET) processes. ESA, typically a two-photon UC process usually only occurs at low level doping concentrations of a single RE ion type. It is a single ion mechanism where a photon from the incident source of radiation excites the ion from its ground state to an intermediate excited state. Excitation from the ground state to an intermediate excited state is known as ground state absorption (GSA). The absorption of the second photon then excites the ion to a higher excited state. Similar to ESA, the ET UC process occurs at higher level doping concentrations. In the ET process, photons from the incident source of radiation excite two separate localized ions in close proximity to an intermediate excited state. From here one ion will act as a sensitizer, relax, and nonradiatively transfer its energy to the neighboring ion resulting in the population of a higher emitting state. Radiative transitions back to the ground state result in visible emissions.<sup>[3]</sup> The nature of these processes is dependent upon the RE dopant types and concentrations within an optically inactive host lattice. Many host lattices have been used for UC which include but not limited to oxides, oxysulfides, and halides.<sup>[4-11]</sup> The REs' 4f electrons are well shielded by the outer 5s and 5p orbitals therefore little interaction exists



between the host lattice and the RE 4f electrons. This allows for the REs' excited states to remain at particular energies which result in strong narrow-line emissions.<sup>[12]</sup>

Erbium ( $Er^{3+}$ ) has been the most extensively studied activator ion for UC due to its unique electronic energy level design of uniformly spaced long-lived excited states.<sup>[13]</sup> This allows  $Er^{3+}$  to exhibit UC luminescence at multiple different NIR excitation wavelengths including 808, 980, and 1560 nm. However, most literature articles on UC report using a 980 nm laser diode as there excitation source. Thus, many phosphors are sensitized with ytterbium (Yb<sup>3+</sup>) in order to increase the conversion efficiency. Yb<sup>3+</sup> has a high absorption cross-section in the NIR regime (~ 1000 nm) making it a first-rate sensitizer to 980 nm radiation. Co-doping  $Er^{3+}$  with Yb<sup>3+</sup> increases the efficiency of the 980 nm UC process due to the spectral overlap of (Yb<sup>3+</sup>)  ${}^{2}F_{5/2} \rightarrow {}^{2}F_{7/2}$  NIR emission band and ( $Er^{3+}$ )  ${}^{4}I_{11/2} \leftarrow {}^{4}I_{15/2}$  absorption band and the majority of visible light generated is due to the resonant ET from Yb<sup>3+</sup> to  $Er^{3+}$ .<sup>[14]</sup>

Research in the upconverting technology field is currently being contributed to a variety of promising applications involving sensors, displays, backlights, anti-forgery markings, and communication optics.<sup>[15-17]</sup> The Yb<sup>3+</sup>,  $Er^{3+}$  co-doped oxysulfide phosphors (Ln<sub>2</sub>O<sub>2</sub>S, Ln = Y<sup>3+</sup>, Yttrium; La<sup>3+</sup>, Lanthanum; or Gd<sup>3+</sup>, Gadolinium) are currently the market's best green upconverting material with medium phonon energy (~ 520 cm<sup>-1</sup>) under 980 nm excitation. It is well known that the halide lattices have the lowest phonon energies and are the most efficient UC materials known to date. However, they are not considered chemically stable or environmentally safe for practical use and also are



moisture sensitive. In comparison, the Y<sub>2</sub>O<sub>2</sub>S phosphor is not only environmentally friendly but also has much better stability both chemically and thermodynamically.<sup>[17]</sup> Thus, Y<sub>2</sub>O<sub>2</sub>S is a promising host material in various luminescent applications both current and future.

Various techniques have been reported for synthesizing RE doped UC oxysulfide phosphors including co- and homogenous precipitation, solution combustion, hydrothermal and solvothermal processes, and solid state flux methods.<sup>[2, 18-22]</sup> However, most of what is reported still requires multiple step processing, high temperatures, lengthy reaction times, and an inert, reducing or sulfurizing atmosphere in order to completely synthesize pure phase oxysulfide phosphors.

Currently, there are few articles available which report on the UC luminescence properties of bulk (micron-sized)  $Y_2O_2S:Er^{3+}$ ,  $(Yb^{3+}, Er^{3+})$  phosphors with respect to dopant concentrations under NIR excitation. Most of what is reported discuss the UC luminescence properties associated with nano-sized oxysulfide phosphors (particle sizes < 100 nm) under 980 nm NIR excitation only. Here, we take advantage of  $Er^{3+}$  unique electronic energy level design and report for the first time the UC luminescence properties and mechanisms related to  $Y_2O_2S:Er^{3+}$ ,  $(Yb^{3+}, Er^{3+})$  phosphors with varying doping concentrations under 808, 980, and 1560 nm radiation. To achieve this goal, the well known polysulfide flux method was used to synthesize the bulk  $Y_2O_2S:Er^{3+}$ ,  $(Yb^{3+}, Er^{3+})$  doped phosphors.<sup>[22-24]</sup> The as-prepared oxysulfide phosphors are produced in a single step and in high purity after washing with dilute acid.



# 2. Experimental



### 2.1 Reagents Used

Yttrium(III) oxide (99.99% Y<sub>2</sub>O<sub>3</sub>), Ytterbium(III) oxide (99.9% Yb<sub>2</sub>O<sub>3</sub>),

Erbium(III) oxide (99.9%  $\text{Er}_2\text{O}_3$ ), Sodium carbonate (ReagentPlus  $\geq$  99.0% Na<sub>2</sub>CO<sub>3</sub>), and Lithium carbonate (purum  $\geq$  99.0% Li<sub>2</sub>CO<sub>3</sub>) were purchased from Sigma Aldrich. Sulfur powder (~ 100 mesh, 99.5% S) was purchased from Alfa Aesar and Potassium phosphate tribasic heptahydrate (ACS grade  $\geq$  98.0%, K<sub>3</sub>PO<sub>4</sub> · 7H<sub>2</sub>O) was purchased from VWR. All reagents were used without any further purification treatment.

### 2.2 Synthesis

The  $Y_{(2-x-y)}O_2S:Yb_x^{3+}$ ,  $Er_y^{3+}$  upconverting phosphors were prepared in a single step using a modified solid state method involving a Na<sub>2</sub>CO<sub>3</sub>/Li<sub>2</sub>CO<sub>3</sub>/K<sub>3</sub>PO<sub>4</sub>-Sulfur flux in a reducing environment. In a typical experiment, stoichometric amounts of Y<sub>2</sub>O<sub>3</sub>, Yb<sub>2</sub>O<sub>3</sub>, and Er<sub>2</sub>O<sub>3</sub> were thoroughly mixed in methanol. Once air dried the RE oxide mixture was ground with Na<sub>2</sub>CO<sub>3</sub> (50 wt % of Y<sub>2</sub>O<sub>3</sub>), S (80 wt % of Y<sub>2</sub>O<sub>3</sub>), Li<sub>2</sub>CO<sub>3</sub> (8 wt % of Y<sub>2</sub>O<sub>3</sub>), and K<sub>3</sub>PO<sub>4</sub> 7H<sub>2</sub>O (20 wt % of Y<sub>2</sub>O<sub>3</sub>) using an agate mortar and pestle. The precursor mixture was transferred to a small alumina crucible and covered. The covered crucible was then placed inside a larger crucible containing an excess of activated carbon. This was also covered in order to maintain the reducing atmosphere needed to inhibit the formation of oxides. The oxysulfide precursor mixture was then heat treated in a Thermo Scientific Type FD1545M Furnace for 3h at 1100°C at a ramp rate of 10°C min<sup>-1</sup>. After



cooling to room temperature, the as-formed product was collected and washed with 5% (v/v) 70% HNO<sub>3</sub> and DI H<sub>2</sub>O several times and dried overnight at 70°C in a vacuum oven.

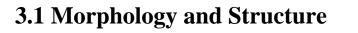
## 2.3 Characterization Techniques

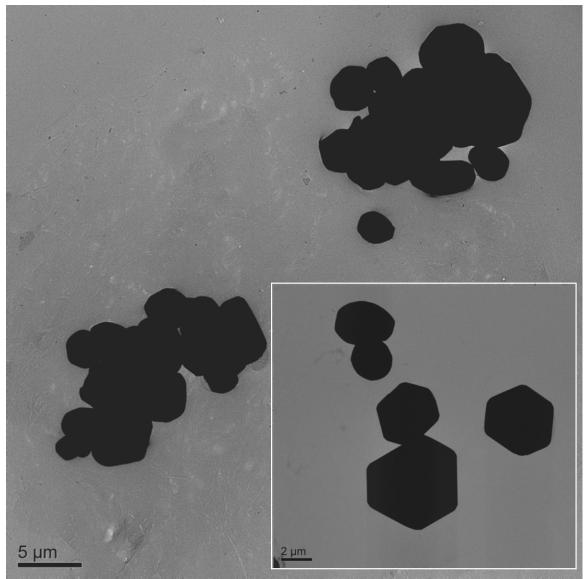
The morphology and structure of the as-prepared particles were characterized using TEM (Joel JEM-1230 operated at 120 kV) and XRD (X'Pert Philips Materials Research diffractometer, with Cu K $\alpha$  radiation). The upconverting luminescence spectra were obtained using a Tau 3 steadystate and lifetime (Horiba Jobin Yvon) spectrofluormeter equipped with external, continuous wave 808, 980, and 1560 nm OEM lab lasers (Laserglow Technologies). It should be noted that the output power for each laser is adjustable therefore a Newport power meter Model 2930C was used to accurately determine the output power necessary for power dependence measurements.



# **3. Results and Discussion**





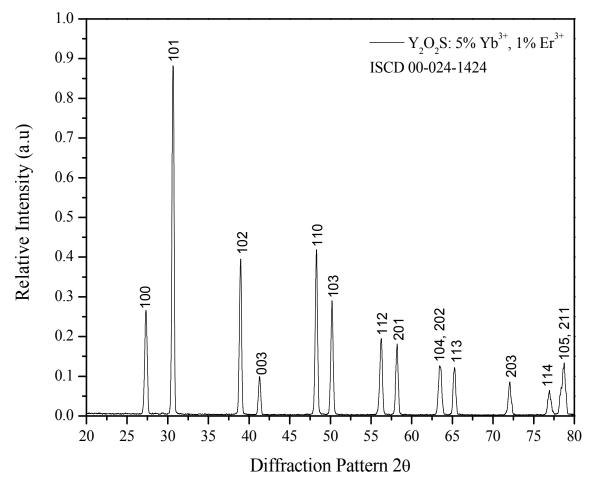


**Figure 1** TEM images of  $Yb^{3+}$  and  $Er^{3+}$  co-doped  $Y_2O_2S$  phosphors.



Figure 1 displays a typical TEM image of an as-prepared oxysulfide sample doped with 5% (mol) Yb<sup>3+</sup> and 1%  $Er^{3+}$ . The oxysulfide phosphors clearly exhibit a spherical morphology with the exception of a few irregular hexagonal facet pieces (shown in the inset). A wide particle size distribution ranging from 2 - 5 µm is clearly observed. However, using the Scherer equation the crystallite size was determined to be 35 nm, respectively. Thus, the irregular morphology and large distribution of particle sizes is attributed to the aggregation of crystallites which had agglomerated during the calcination process in order to minimize the surface area energy resulting in large particle formations. It should be noted that similar results have also been reported using a combustion synthesis for the preparation of oxysulfide phosphors. High and low-resolution SEM images demonstrated that the 10 - 30 µm particles were actually comprised of numerous much smaller particles ranging from 100 to 200 nm that had agglomerated to form large porous structures.<sup>[19]</sup>





**Figure 2** XRD pattern of an Y<sub>2</sub>O<sub>2</sub>S sample prepared using the polysulfide flux method showing pure hexagonal phase with the hkl crystalline planes shown.



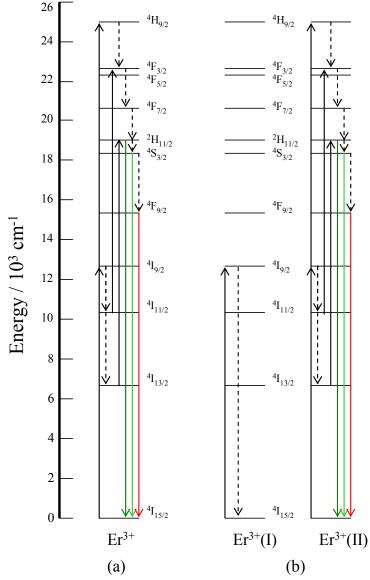
Figure 2 shows the XRD powder diffraction pattern of the corresponding 5%  $Yb^{3+}$ , 1%  $Er^{3+}$  co-doped  $Y_2O_2S$  sample from Figure 1 matching the ICSD Index file 00-024-1424. It is important to note that only  $Y_2O_2S$  is observed with no sign of  $Y_2O_3$  or fluxing agents present which is indicative that the sulfurization process of  $Y_2O_3$  was complete. Also, the absence of  $Yb_2O_2S$  and  $Er_2O_2S$  diffraction peaks suggests that the  $Yb^{3+}$  and  $Er^{3+}$  ions are well dispersed throughout the  $Y_2O_2S$  lattice. Thus,  $Yb^{3+}$  and  $Er^{3+}$  co-doped  $Y_2O_2S$  phosphors can successfully be prepared at 1100°C for 3h in high purity using the methodology described here.



## **3.2 IR to VIS Upconversion**

## 3.2.1 Y<sub>2</sub>O<sub>2</sub>S:Er<sup>3+</sup> Phosphors

### 3.2.1.1 808 nm Excitation



**Figure 3** Schematic: (a) ESA and (b) ET UC processes occurring at the  ${}^{4}I_{13/2}$ ,  ${}^{4}I_{11/2}$ , and  ${}^{4}I_{9/2}$  states under 808 nm excitation.



The energy level schematic of the ESA and ET UC processes occurring at the  ${}^{4}I_{13/2}$ ,  ${}^{4}I_{11/2}$  and  ${}^{4}I_{9/2}$  states along with the luminescence emissions and non-radiative transitions under 808 nm excitation are shown in Figure 3, a and b. In the ESA process (Figure 3a), a single  $Er^{3+}$  ion is excited from the  ${}^{4}I_{15/2}$  ground state to the  ${}^{4}I_{9/2}$  excited state, via GSA. A second 808 nm photon then excites  $Er^{3+}$  from the  ${}^{4}I_{9/2}$  state to the higher  ${}^{2}H_{9/2}$  state. ESA is also known to occur at the  ${}^{4}I_{11/2}$  state as the result of nonradiative decay from the <sup>4</sup>I<sub>9/2</sub> state after the absorption of the initial photon. A second incoming photon is then absorbed and excites  $Er^{3+}$  to the higher  ${}^{4}F_{3/2}$  state. Alternatively,  $\mathrm{Er}^{3+}$  ions that non-radiatively decay to the  ${}^{4}\mathrm{I}_{11/2}$  state can decay again to the  ${}^{4}\mathrm{I}_{13/2}$  state where ESA of a second photon results in the population of the  ${}^{2}H_{11/2}$  emitting state. In the ET process (Figure 3b), two neighboring  $Er^{3+}$  ions are simultaneously excited to the  ${}^{4}I_{9/2}$ state. From here, one  $Er^{3+}$  ion will relax back to the  ${}^{4}I_{15/2}$  ground state and transfer its energy to the neighboring  $Er^{3+}$  ion resulting in the direct population of the higher  ${}^{2}H_{9/2}$ state. Alternatively, one  $Er^{3+}$  ion can non-radiatively decay to either the  ${}^{4}I_{11/2}$  or the  ${}^{4}I_{13/2}$ states where ET from the neighboring  $Er^{3+}$  ion results in population of the  ${}^{4}F_{3/2}$  and  ${}^{2}H_{11/2}$ states.  $^{[25]}$  A series of non-radiative transitions from the higher  $^4H_{9/2}$  and  $^4F_{3/2}$  states result in the population of the  ${}^{2}H_{11/2}$ ,  ${}^{4}S_{3/2}$  and  ${}^{4}F_{9/2}$  emitting states where spin-allowed transitions back to the  ${}^{4}I_{15/2}$  ground state result in green emissions around 530 and 550 nm and red emissions around 660 - 670 nm.

It is important to mention that the room temperature UC emission spectra obtained for all samples, independent of dopant concentration and excitation wavelength



have the same spectral profile where the green and red emissions occurring near 530 and 550 nm and 660 - 670 nm are consistent with the  $({}^{2}H_{11/2})^{4}S_{3/2} \rightarrow {}^{4}I_{15/2}$  and  ${}^{4}F_{9/2} \rightarrow {}^{4}I_{15/2}$  transitions, respectively.

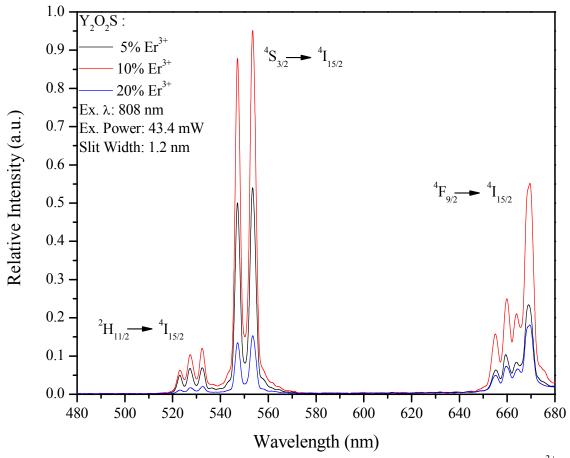


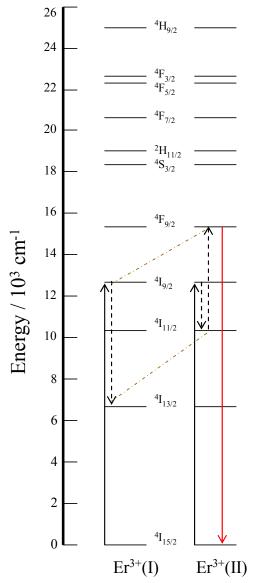
Figure 4 UC emission spectra of  $Y_2O_2S$  phosphors doped with 5%, 10% and 20%  $Er^{3+}$ .

Figure 4 shows the room temperature UC emission spectra of  $Y_2O_2S$  phosphors doped with 5%, 10%, and 20%  $Er^{3+}$  under 808 nm excitation operating with an output power of 43.4 mW. Doubling the  $Er^{3+}$  concentration from 5% to 10% showed significant enhancement on the luminescence intensity for both the green and red emission bands.



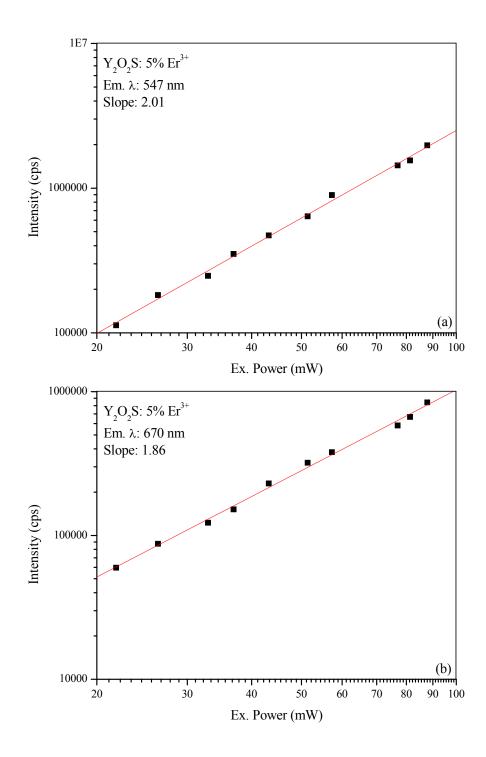
This increase in emission intensity is a result of ET between  $Er^{3+}$  ions in close proximity. When compared to the 5%  $Er^{3+}$  doped sample, the intensity of the green emission for the 20%  $Er^{3+}$  doped sample decreased considerably as result of concentration quenching where  $Er^{3+}$  ions are no longer able to reach the  ${}^{2}H_{11/2}$  emitting state. However, the intensity of the red emission for both the 5 and 20%  $Er^{3+}$  doped samples remained about the same, respectively. This is because there are two different pathways in which the  ${}^{4}F_{9/2}$  state can most likely be populated when excited by 808 nm: (1) relaxation from the  ${}^{2}H_{11/2}$  state and (2) the  ${}^{4}I_{9/2} Er^{3+}(I) + {}^{4}I_{11/2} Er^{3+}(II) \rightarrow {}^{4}F_{13/2} Er^{3+}(I) + {}^{4}F_{9/2} Er^{3+}(II)$  cross-relaxation process.<sup>[7], [25]</sup> This alternate pathway for populating the  ${}^{4}F_{9/2}$  emitting state shown below in Figure 5 could possibly be responsible for the majority of red luminescence being emitted in high  $Er^{3+}$  doped oxysulfide phosphors under 808 nm excitation.



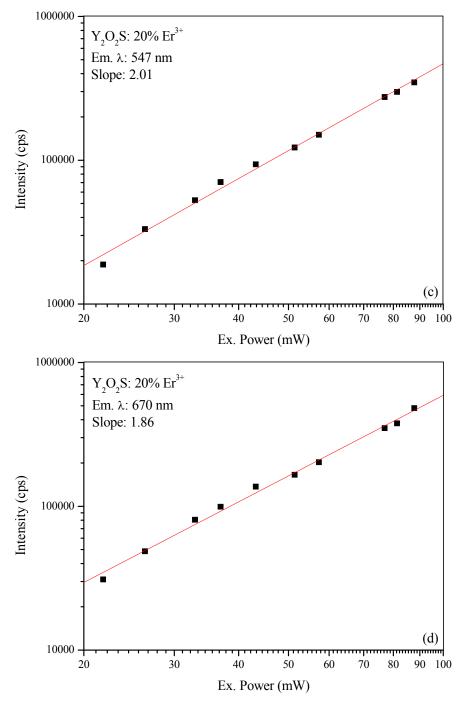


**Figure 5** Schematic:  ${}^{4}I_{9/2}Er^{3+}(I) + {}^{4}I_{11/2}Er^{3+}(II) \rightarrow {}^{4}F_{13/2}Er^{3+}(I) + {}^{4}F_{9/2}Er^{3+}(II)$  cross-relaxation process possibly responsible for the  ${}^{4}F_{9/2}$  state in high  $Er^{3+}$  doped oxysulfide phosphors under 808 nm excitation.









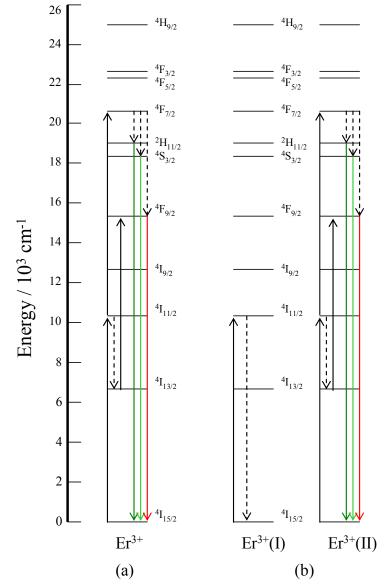
**Figure 6** Power dependence of UC intensity of  $Y_2O_2S$  phosphors doped with 5%  $Er^{3+}$  and 20%  $Er^{3+}$  monitored at (a), (c) 547 nm, and (b), (d) 670 nm under 808 nm excitation.



It is well known that the UC intensity (I) and the excitation power (P) are dependant upon one another according to the equation  $I \approx P^n$ , where *n* is the number of NIR photons required to excite ions to a higher emitting state. The slope from a log<sub>10</sub> scale where the luminescent emission intensity of a particular wavelength plotted against the excitation power will give the number of NIR pumping photons used in the UC process. It should be noted, that all power dependence measurements were made monitoring the 547 and 670 nm emission peaks which were the most intense in the green and red spectral regions.

Figure 6 shows the power dependence of UC intensity of  $Y_2O_2S$  phosphors doped with (a), (b) 5%  $Er^{3+}$ , and (c), (d) 20%  $Er^{3+}$ . From the power dependence plots, the UC emissions monitored at 547 nm and 670 nm required 2.01 and 1.86 photons for both the 5%  $Er^{3+}$  and 20%  $Er^{3+}$  doped samples. Even though the number of NIR pumping photons required to populate the  ${}^{4}S_{3/2}$  and  ${}^{4}F_{9/2}$  emitting states for both the 5% and 20%  $Er^{3+}$  doped sample remained the same, respectively, it does not necessarily rule out the possibility of this cross-relaxation mechanism. Population of the  ${}^{4}F_{9/2}$  emitting state either by, the nonradiative  ${}^{2}H_{11/2} \rightarrow {}^{4}F_{9/2}$  transition or the  ${}^{4}I_{9/2} Er^{3+}(I) + {}^{4}I_{11/2} Er^{3+}(II) \rightarrow {}^{4}F_{13/2} Er^{3+}(I) + {}^{4}F_{9/2}$  $Er^{3+}(II)$  cross-relaxation mechanism would still require a two-photon excitation process. However, it is most likely that the decrease in intensity observed in both the green and red emission bands is due to concentration quenching where the back transfer of energy between the  $Er^{3+}$  ions results in inefficient UC and at a 20% doping concentration this would be expected.



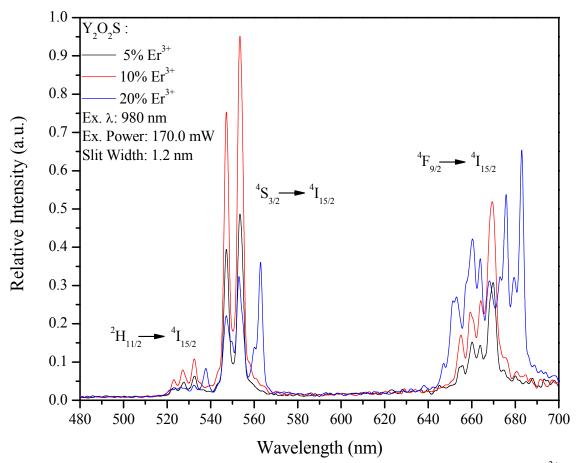


### 3.2.1.2 980 nm Excitation

**Figure 7** Schematic: (a) ESA and (b) ET UC processes occurring at the  ${}^{4}I_{11/2}$  and  ${}^{4}I_{13/2}$  states under 980 nm excitation.



The energy level schematics of the ESA and ET UC processes occurring at the  ${}^{4}I_{11/2}$  and  ${}^{4}I_{13/2}$  states along with the luminescence emissions and non-radiative transitions under 980 nm excitation are shown in Figure 7, a and b. In Figure 7a, a single  $Er^{3+}$  ion is excited from the  ${}^{4}I_{15/2}$  ground state to the  ${}^{4}I_{11/2}$  excited state, via GSA. A second incoming 980 nm photon is then absorbed and excites  $Er^{3+}$  to the higher  ${}^{4}F_{7/2}$  state. ESA is also to known to occur at the  ${}^{4}I_{13/2}$  state as the result of non-radiative decay from the  ${}^{4}I_{11/2}$  state after the absorption of the initial photon. A second incoming photon is then absorbed exciting  $Er^{3+}$  directly to the  ${}^{4}F_{9/2}$  state. In the ET process (Figure 7b), two neighboring  $Er^{3+}$  ions are simultaneously excited to the  ${}^{4}I_{11/2}$  intermediate state. From here, one  $Er^{3+}$  ion will relax back to its ground state and transfer its energy to the neighboring  $Er^{3+}$  ions can decay to the  ${}^{4}I_{13/2}$  state where ET from the neighboring  $Er^{3+}$  ion results in population of the  ${}^{4}F_{9/2}$  state. Non-radiative relaxation from the higher  ${}^{4}F_{7/2}$  excited state results in the population of the  ${}^{2}H_{11/2}$ ,  ${}^{4}S_{3/2}$ , and  ${}^{4}F_{9/2}$  emitting states.



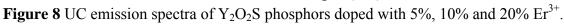
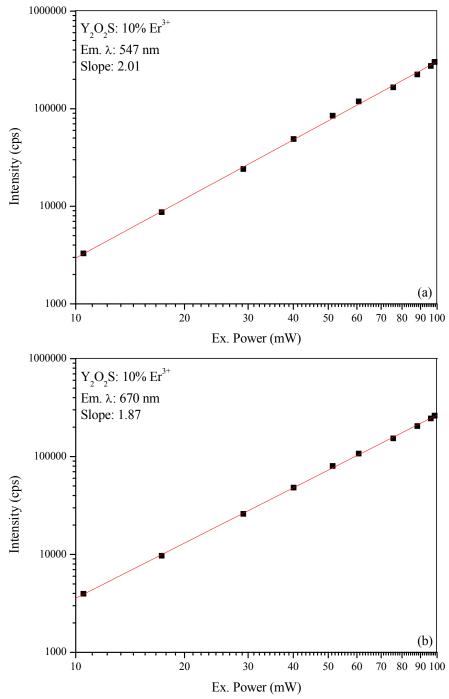


Figure 8 shows the room temperature UC emission spectra of  $Y_2O_2S$  phosphors doped with 5%, 10%, and 20%  $Er^{3+}$  under 980 nm excitation operating with an output power of 170 mW. Doubling the  $Er^{3+}$  concentration from 5% to 10% showed significant enhancement on the luminescence intensity for both the green and red emission bands. This increase in emission intensity is a result of ET between  $Er^{3+}$  atoms in close proximity. The 20%  $Er^{3+}$  doped sample exhibited unique spectral broadening of both luminescence bands with additional peak formations previously not seen when subjected



to 808 nm excitation. This is due to incomplete sulfurization of  $Y_2O_3$  and where the spectral profile of the red emission band matches that of the bulk  $Yb^{3+}$  and  $Er^{3+}$  co-doped  $Y_2O_3$  phosphors. Thus, it is concluded that when doping with higher  $Er^{3+}$  concentrations longer reaction times are required in order to complete the sulfurization process.





**Figure 9** Power dependence of UC intensity of the  $Y_2O_2S$  phosphor doped with 10%  $Er^{3+}$  monitored at (a) 547 nm, and (b) 670 nm under 980 nm excitation.



Figure 9 shows the power dependence of UC intensity of 10%  $Er^{3+}$  doped  $Y_2O_2S$  phosphor monitored at (a) 547 nm and (b) 670 nm. From the power dependence plots, the UC emissions monitored at 547 nm and 670 nm required 2.01 and 1.87 photons for the 10%  $Er^{3+}$  doped sample. It is interesting to note that the power dependence measurements monitoring the 547 and 670 nm emission peaks showed that singly doped  $Er^{3+}Y_2O_2S$  phosphors, independent of concentration, have the same linear power dependence under both 808 and 980 nm excitation where the number of NIR pumping photons required to generate both the 547 and 670 nm emission peaks remained the same, respectively.



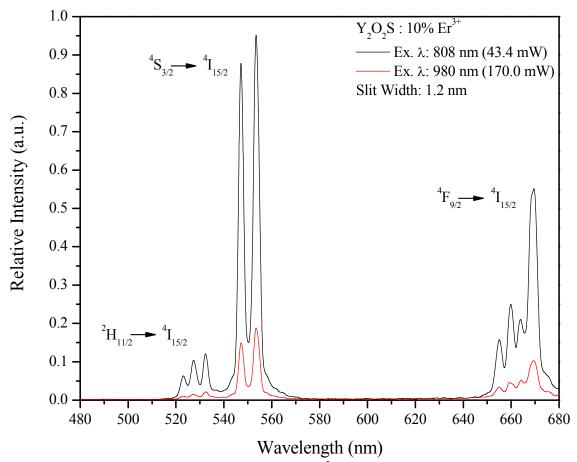
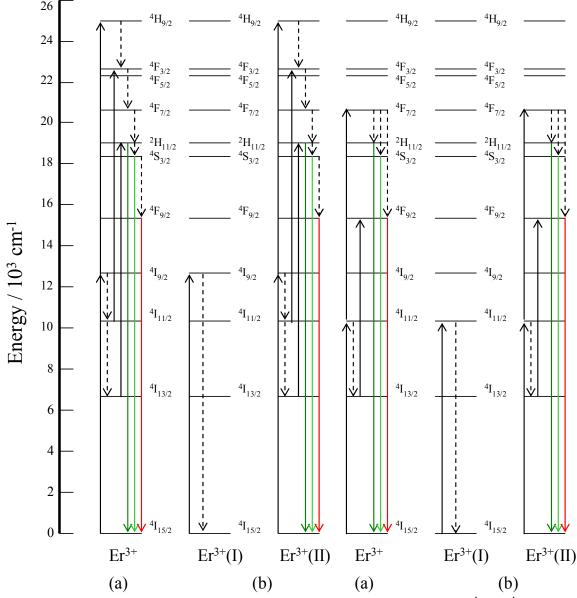


Figure 10 UC emission spectra of  $Y_2O_2S$ : 10%  $Er^{3+}$  phosphors under 808 and 980 nm excitation.

Figure 10 shows the room temperature UC emission spectra of the 10%  $\text{Er}^{3+}$ doped Y<sub>2</sub>O<sub>2</sub>S phosphors under 808 and 980 nm excitation. The difference in the emission intensities suggests that the UC process in singly doped  $\text{Er}^{3+}$  Y<sub>2</sub>O<sub>2</sub>S phosphors is much more efficient under 808 than 980 nm excitation which is not at all surprising. It is well known, that without the presence of Yb<sup>3+</sup> acting as a sensitizer that the efficiency of the UC process ultilizing 980 nm excitation is rather inefficient. In addition to having the same power dependence upon 808 and 980 nm excitation, Figure 10 also shows that the



spectral profiles of the UC emission bands remain the same. Thus, the only major difference is how this process is occurring mechanistically and the subtle differences in the UC mechanisms is more obvious when directly compared and is shown in Figure 11.



**Figure 11** Schematic: (a) ESA and (b) ET UC processes occurring at the  ${}^{4}I_{13/2}$ ,  ${}^{4}I_{11/2}$ , and  ${}^{4}I_{9/2}$  states under 808 nm (left) and  ${}^{4}I_{11/2}$ , and  ${}^{4}I_{9/2}$  states under 980 nm excitation (right).



Figure 11 shows the schematic illustrations of the ESA and ET UC processes occurring at the  ${}^{4}I_{13/2}$ ,  ${}^{4}I_{11/2}$ , and  ${}^{4}I_{9/2}$  states under 808 nm (left) and  ${}^{4}I_{11/2}$ , and  ${}^{4}I_{9/2}$  states under 980 nm excitation (right). When compared side by side the slight differences in the UC mechanisms become more apparent and can be clearly established. The non-radiative  ${}^{4}I_{9/2} \rightarrow {}^{4}I_{11/2}$ ,  ${}^{4}I_{13/2}$  and  ${}^{4}I_{11/2} \rightarrow {}^{4}I_{13/2}$  transitions which can occur following GSA of an 808 nm photon, will not affect the population of the higher green and red emitting states. Depending on which excited state  $Er^{3+}$  is in following GSA and considering the nonradiative transitions, ESA or ET will either directly populate the  ${}^{2}H_{11/2}$  emitting state from the  ${}^{4}I_{9/2}$  state or indirectly through series of non-radiative transitions from the higher  ${}^{4}H_{9/2}$ or  ${}^{4}F_{3/2}$ ,  ${}^{4}F_{5/2}$  states. As a result, the  ${}^{2}H_{11/2}$  emitting state is solely responsible for the population of the  ${}^{4}S_{3/2}$  and  ${}^{4}F_{9/2}$  emitting states and therefore essential for UC under 808 nm excitation. Immediately following GSA of a 980 nm photon, the ESA or ET UC processes which are known to occur at both the  ${}^{4}I_{11/2}$  and the  ${}^{4}I_{13/2}$  intermediate states will result in different wavelengths to be emitted. ESA or ET from the <sup>4</sup>I<sub>11/2</sub> state results in indirect population of the  ${}^{2}H_{11/2}$ ,  ${}^{4}S_{3/2}$ , and  ${}^{4}F_{9/2}$  emitting states through non-radiative relaxation from the higher  ${}^{4}F_{7/2}$  state and as a result both green and red emissions can be produced. However, ESA or ET from the  ${}^{4}I_{13/2}$  state as a result of the non-radiative  ${}^{4}I_{11/2}$  $\rightarrow$  <sup>4</sup>I<sub>13/2</sub> transition following GSA, directly populates the <sup>4</sup>F<sub>9/2</sub> state only and as a result only a red emission will be produced. This alternate pathway decreases the likelihood of populating the higher  ${}^{2}H_{11/2}$  and  ${}^{4}S_{3/2}$  emitting states and as a result the efficiency of the

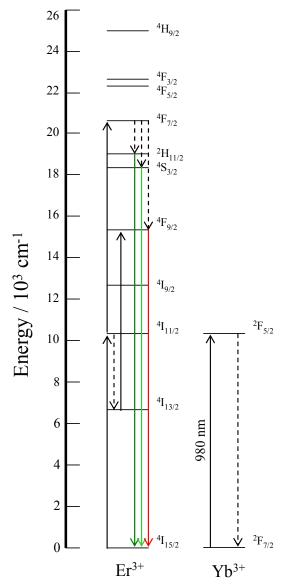


980 nm UC process with respect to the green emissions corresponding to the radiative  ${}^{2}\text{H}_{11/2}$ ,  ${}^{4}\text{S}_{3/2} \rightarrow {}^{4}\text{I}_{15/2}$  transitions will be decreased.

It is noteworthy to mention that the UC luminescence properties regarding spectral emission profiles, dependence on the excitation power, and mechanisms for singly doped  $Er^{3+} Y_2O_2S$  phosphors occurring under 808 and 980 nm excitation has not been directly compared in the established literature and is reported here for the first time.



# 3.2.2 Y<sub>2</sub>O<sub>2</sub>S:Yb<sup>3+</sup>, Er<sup>3+</sup> Phosphors under 980 nm Excitation 3.2.2.1 Fixing Yb<sup>3+</sup> and Increasing Er<sup>3+</sup>

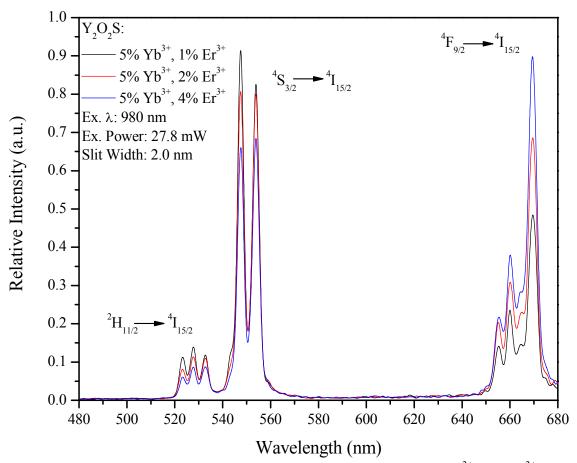


**Figure 12** Schematic of the ET UC process from  $Yb^{3+}$  to  $Er^{3+}$  occurring at the  ${}^{4}I_{11/2}$  and  ${}^{4}I_{13/2}$  states under 980 nm excitation.



The energy level schematic of the resonant ET UC process occurring at the  ${}^{4}I_{11/2}$ and  ${}^{4}I_{13/2}$  states along with the luminescence emissions and non-radiative transitions under 980 nm excitation are shown in Figure 12. Upon 980 nm excitation the first Yb<sup>3+</sup> ion transfers its energy to the ground state of Er<sup>3+</sup> exciting it to the  ${}^{4}I_{11/2}$  state. A second excited Yb<sup>3+</sup> ion then relaxes and transfers its energy to the same excited neighboring Er<sup>3+</sup> atom resulting in the population of the  ${}^{4}F_{7/2}$  state. Non-radiative relaxation from the higher  ${}^{4}F_{7/2}$  state results in the population of the  ${}^{2}H_{11/2}$ ,  ${}^{4}S_{3/2}$  and  ${}^{4}F_{9/2}$  emitting states. However, immediately following the first initial ET from Yb<sup>3+</sup>, Er<sup>3+</sup> can non-radiatively decay to the  ${}^{4}I_{13/2}$  state where now the second resonant ET from Yb<sup>3+</sup> will result in the population of the  ${}^{4}F_{9/2}$  emitting state only.





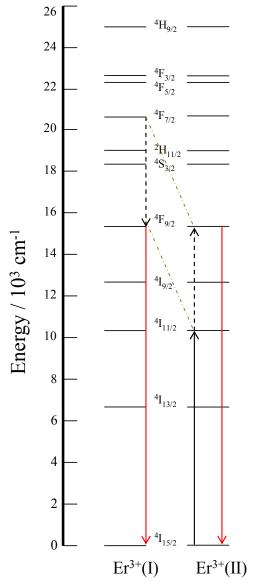
**Figure 13** UC emission spectra of  $Y_2O_2S$  phosphors doped with 5%  $Yb^{3+}$ , X%  $Er^{3+}$ , where X ranges from 1.0 - 4.0.

Figure 13 shows the room temperature UC emission spectra of  $Y_2O_2S$  phosphors doped with 5% Yb<sup>3+</sup> and X% Er<sup>3+</sup>, where X ranges from 1.0 - 4.0 under 980 nm excitation operating with an output power of 27.8 mW. Increasing the Er<sup>3+</sup> concentration in the fixed Yb<sup>3+</sup> doped phosphors lead to an increase in the intensity of the red emission band while subsequently lead to a decrease in the intensity of the green emission bands. It is important to note that the emission pathways corresponding to the ( ${}^{2}H_{11/2}$ ) ${}^{4}S_{3/2}$ ,  ${}^{4}F_{9/2} \rightarrow$  ${}^{4}I_{15/2}$  transitions are directly affected and dependent upon the Er<sup>3+</sup> concentration. Higher



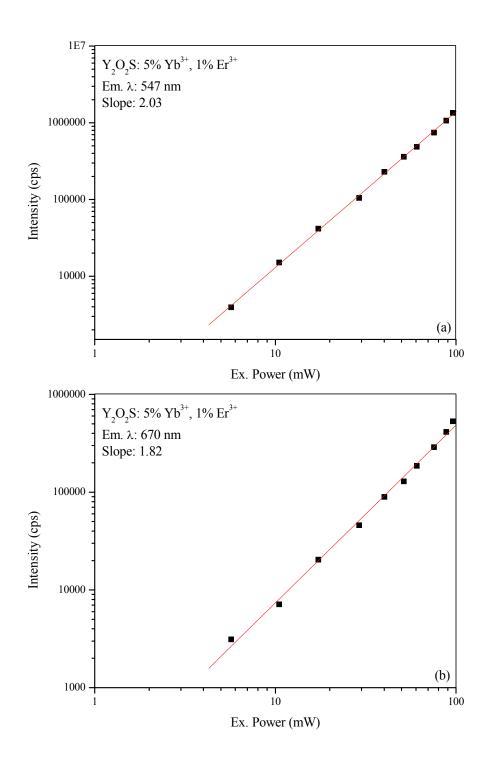
 $Er^{3+}$  concentrations lead to higher tendency for interactions between neighboring  $Er^{3+}$ ions. Therefore, it has been proposed by several authors studying  $Yb^{3+}$  and  $Er^{3+}$  codoped nanocrystalline Y<sub>2</sub>O<sub>3</sub> phosphors that the non-radiative  ${}^{4}F_{7/2} \rightarrow {}^{4}F_{9/2}$  transition not only results in a red emission around 660 nm but also directly populates the  ${}^{4}F_{9/2}$  state of a neighboring excited  $\text{Er}^{3+}$  ion from the  ${}^{4}\text{I}_{11/2}$  state via the  ${}^{4}\text{F}_{7/2}$   $\text{Er}^{3+}(I) + {}^{4}\text{I}_{11/2}$   $\text{Er}^{3+}(II) \rightarrow$  ${}^{4}F_{9/2} \operatorname{Er}^{3+}(I) + {}^{4}F_{9/2} \operatorname{Er}^{3+}(II)$  cross-relaxation mechanism shown below in Figure 14.<sup>[3], [4],</sup> [8], [14] It should be noted that when the  $Er^{3+}$  concentration reached 4% the intensity of the red emission band became more intense than the intensity of the green emission band. The decrease in the green emission intensity observed when the  $Er^{3+}$  concentration is increased is not a result of concentration quenching but could possibly be, to a lesser extent, a result of this cross-relaxation mechanism. Although, this would explain the significant increase in the intensity of red emission observed, cross-relaxation between Er<sup>3+</sup> ions is highly unlikely due to the low dopant concentration. A simpler explanation for the observable changes in the intensities would be that when the  $Er^{3+}$  concentration reaches nearly that of Yb<sup>3+</sup> the efficiency of the non-radiative  ${}^{4}F_{7/2} \rightarrow {}^{4}F_{9/2}$  and  ${}^{4}I_{13/2} \rightarrow$  ${}^{4}I_{15/2}$  transitions becomes increased.



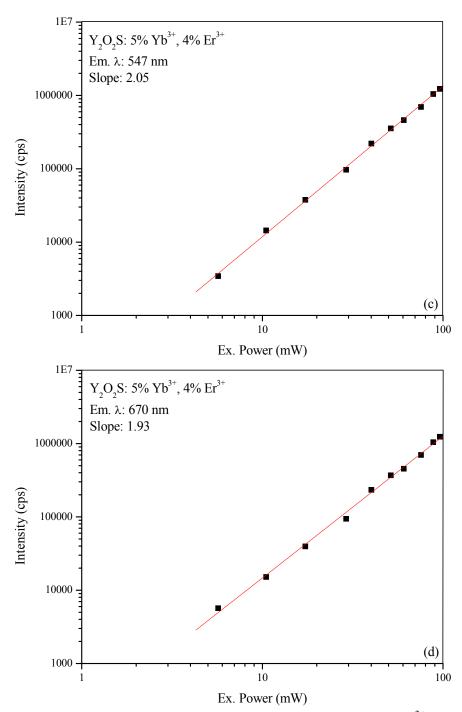


**Figure 14** Schematic:  ${}^{4}F_{7/2}Er^{3+}(I) + {}^{4}I_{11/2}Er^{3+}(II) \rightarrow {}^{4}F_{9/2}Er^{3+}(I) + {}^{4}F_{9/2}Er^{3+}(II)$  cross-relaxation process possibly responsible for the  ${}^{4}F_{9/2}$  state under 980 nm excitation.









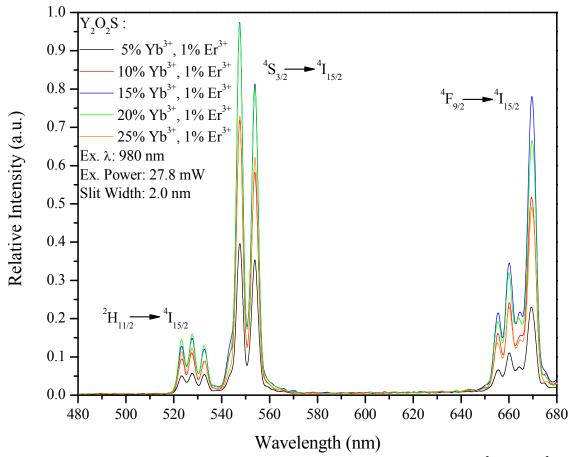
**Figure 15** Power dependence of UC intensity of  $Y_2O_2S$ : 5%Yb<sup>3+</sup> phosphors doped with 1% Er<sup>3+</sup> and 4% Er<sup>3+</sup> monitored at (a), (c) 547 nm, and (b), (d) 670 nm under 980 nm excitation.



Figure 15 shows the power dependence of UC intensity of  $Y_2O_2S$  phosphors doped with (a), (b) 5% Yb<sup>3+</sup>, 1% Er<sup>3+</sup>, and (c), (d) 5% Yb<sup>3+</sup>, 4% Er<sup>3+</sup>. From the power dependence plots, the UC emissions monitored at 547 nm and 670 nm required 2.03 and 1.82 photons for the 1% Er<sup>3+</sup> doped sample and 2.05 and 1.93 photons for the 4% Er<sup>3+</sup> doped sample. Ultimately, this rules out the possibility of this cross-relaxation mechanism since the number of NIR pumping photons required to populate the <sup>4</sup>S<sub>3/2</sub> and <sup>4</sup>F<sub>9/2</sub> emitting states for both the 1% and 4% Er<sup>3+</sup> doped sample remained the same, respectively. Therefore, it is most likely that the changes in the intensity of the green and red emission bands observed in the UC emission spectra are in fact due to the nonradiative <sup>4</sup>F<sub>7/2</sub>  $\rightarrow$  <sup>4</sup>F<sub>9/2</sub> and <sup>4</sup>I<sub>13/2</sub>  $\rightarrow$  <sup>4</sup>I<sub>15/2</sub> transitions which become more predominant as the concentration of Er<sup>3+</sup> is increased.



3.2.2.2 Fixing Er<sup>3+</sup> and Increasing Yb<sup>3+</sup>



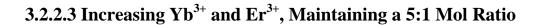
**Figure 16** UC emission spectra of  $Y_2O_2S$  phosphors co-doped with X%  $Yb^{3+}$ , 1%  $Er^{3+}$ , where X ranges from 5.0 - 25.0.

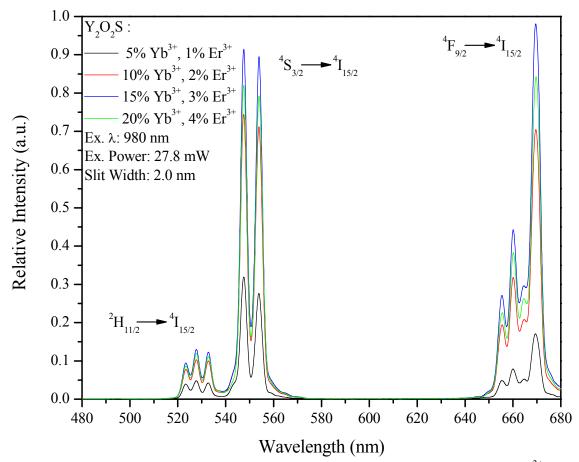
Figure 16 shows the room temperature UC emission spectra of  $Y_2O_2S$  phosphors doped with X% Yb<sup>3+</sup>, 1% Er<sup>3+</sup>, where X is incrementally increased by 5% from 5.0 - 25.0 under 980 nm excitation operating with an output power of 27.8 mW. Increasing the Yb<sup>3+</sup> concentration in the fixed Er<sup>3+</sup> doped phosphors from 5% to 15% caused the intensity of the green and red emission bands corresponding to the ( ${}^{2}H_{11/2}$ ) ${}^{4}S_{3/2}$ ,  ${}^{4}F_{9/2} \rightarrow {}^{4}I_{15/2}$ transitions to increase significantly. However, when the Yb<sup>3+</sup> concentration was increased



to 20% only the intensity of the red emission was decreased whereas the green emission intensity remained unaffected, respectively. The  ${}^{4}I_{13/2}$  state plays an important role in helping generate the red luminescence emission by directly populating the  ${}^{4}F_{9/2}$  emitting state from a second ET from Yb<sup>3+</sup>. Increasing the Yb<sup>3+</sup> concentration to 20% reduced the likelihood for the non-radiative  ${}^{4}I_{11/2} \rightarrow {}^{4}I_{13/2}$  transition to occur as well as the nonradiative  ${}^{4}F_{7/2} \rightarrow {}^{4}F_{9/2}$  transition which resulted in a decrease in red luminescence intensity. This also explains why the green luminescence intensity did not exhibit the same effect and remained unchanged, respectively. It is necessary to note that when the Yb<sup>3+</sup> concentration reaches 25% the emission intensity diminishes as a result of concentration quenching where energy is back transferred to the Yb<sup>3+</sup> ions.





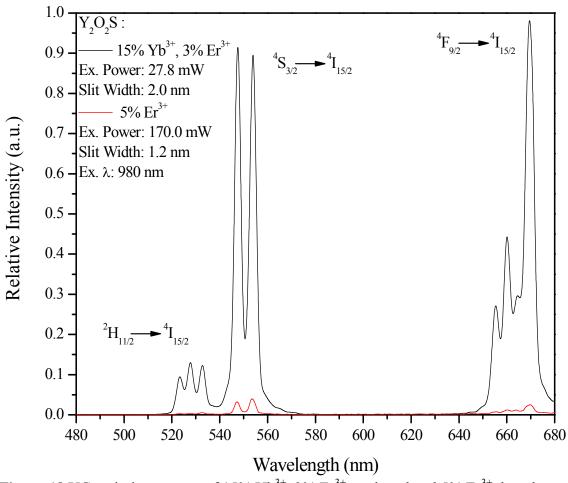


**Figure 17** UC emission spectra of  $Y_2O_2S$  phosphors co-doped with a fixed 5:1 Yb<sup>3+</sup> to  $Er^{3+}$  mol ratio with increasing concentrations.

Figure 17 shows the room temperature UC emission spectra of  $Y_2O_2S$  phosphors doped with different concentrations of  $Yb^{3+}$  and  $Er^{3+}$ , while maintaining a 5:1 mol ratio under 980 nm excitation operating with an output power of 27.8 mW. Increasing the concentration of  $Yb^{3+}$  and  $Er^{3+}$  caused the intensity of the green and red emission bands corresponding to the  $({}^{2}H_{11/2}){}^{4}S_{3/2}$ ,  ${}^{4}F_{9/2} \rightarrow {}^{4}I_{15/2}$  transitions to increase significantly. However, when a 5:1 mol ratio of 20%  $Yb^{3+}$  and 4%  $Er^{3+}$  is incorporated into the  $Y_2O_2S$ 



host lattice the intensity of both the green and red emissions decreased as a result of concentration quenching.



**Figure 18** UC emission spectra of 15% Yb<sup>3+</sup>, 3%  $\text{Er}^{3+}$  co-doped and 5%  $\text{Er}^{3+}$  doped Y<sub>2</sub>O<sub>2</sub>S phosphors under 980 nm excitation.

Figure 18 shows the room temperature UC emission spectra of  $Y_2O_2S$  phosphors co-doped with 15%  $Yb^{3+}$ , 3%  $Er^{3+}$  and doped with 5%  $Er^{3+}$ . A significant enhancement in the UC luminescence intensity for both the green and red emission bands is clearly observed. It is clear from the emission spectra that co-doping  $Er^{3+}$  with  $Yb^{3+}$  significantly

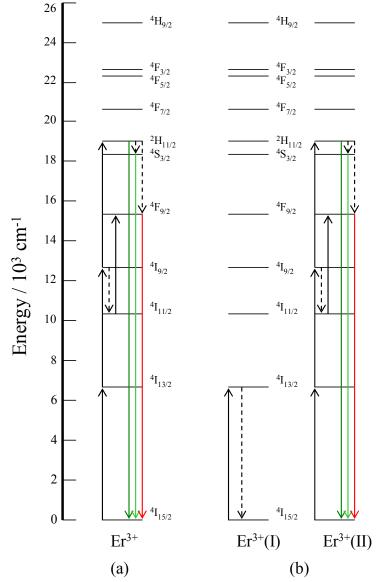


increases the efficiency of the 980 nm UC process as it is well known that the excited state of Yb<sup>3+</sup> possesses a much larger absorption cross-section than the <sup>4</sup>I<sub>11/2</sub> excited state of  $\text{Er}^{3+}$ .<sup>[3]</sup> The increase in the UC efficiency is due solely to the well-defined spectral overlap between (Yb<sup>3+</sup>)  $^{2}F_{5/2} \rightarrow ^{2}F_{7/2}$  NIR emission band and (Er<sup>3+</sup>)  $^{4}I_{11/2} \leftarrow ^{4}I_{15/2}$  absorption band. It is concluded from the emission spectra, that the majority of visible light generated upon 980 nm excitation is due to the resonant ET from Yb<sup>3+</sup> to Er<sup>3+</sup> since the luminescence signal of the 5% Er<sup>3+</sup> doped Y<sub>2</sub>O<sub>2</sub>S phosphors is negligible in comparison.



### 3.2.3 1560 nm Excitation

## 3.2.3.1 Y<sub>2</sub>O<sub>2</sub>S:Er<sup>3+</sup> Phosphors

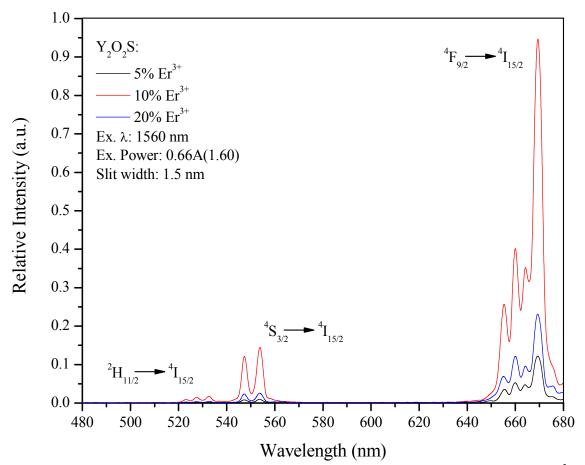






The energy level schematic of the ESA and ET UC processes occurring at the  ${}^{4}I_{13/2}$ ,  ${}^{4}I_{9/2}$ , and  ${}^{4}I_{11/2}$  states along with the luminescence emissions and non-radiative transitions under 1560 nm excitation are shown in Figure 19, a and b. In the ESA process (Figure 19a), a single  $Er^{3+}$  ion is excited from the  ${}^{4}I_{15/2}$  ground state to the  ${}^{4}I_{13/2}$  excited state. A second 1560 nm photon then excites  $\text{Er}^{3+}$  from the  ${}^{4}I_{13/2}$  state to the  ${}^{4}I_{9/2}$  state where finally a third incoming photon excites  $Er^{3+}$  to the  ${}^{2}H_{11/2}$  emitting state. ESA is also known to occur at the  ${}^{4}I_{11/2}$  state as the result of non-radiative decay from the  ${}^{4}I_{9/2}$ state after the absorption of the second incoming photon. A third incoming photon is then absorbed and directly excites  $Er^{3+}$  to the  ${}^{4}F_{9/2}$  emitting state. In the ET process (Figure 19b),  $Er^{3+}$  ions are simultaneously excited to the  ${}^{4}I_{13/2}$  state. From here, multiple  $Er^{3+}$  ions will act as sensitizers, relaxing back to the  ${}^{4}I_{15/2}$  ground state and transfer their energy to the neighboring activator  $\text{Er}^{3+}$  ion resulting in the direct population of the  ${}^{2}\text{H}_{11/2}$  emitting state through a two-step ET process. Alternatively, the activating  $Er^{3+}$  ion can nonradiatively decay to the  ${}^{4}I_{11/2}$  state where ET from the neighboring  $Er^{3+}$  ion results in the direct population of the <sup>4</sup>F<sub>9/2</sub> emitting state.<sup>[24]</sup> Non-radiative transitions from the higher  $^{2}$ H<sub>11/2</sub> emitting state result in the population of the  $^{4}$ S<sub>3/2</sub> and  $^{4}$ F<sub>9/2</sub> emitting states where spin-allowed transitions back to the  ${}^{4}I_{15/2}$  ground state result in green emissions around 530 and 550 nm and red emissions around 660 - 670 nm.





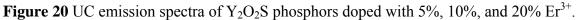
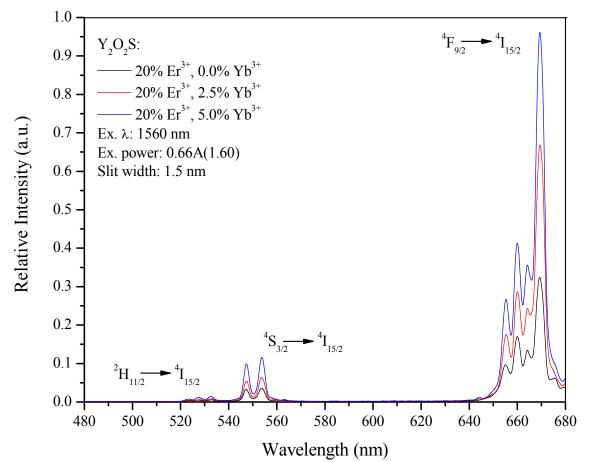


Figure 20 shows the room temperature UC emission spectra of  $Y_2O_2S$  phosphors doped with 5%, 10%, and 20%  $Er^{3+}$  under 1560 nm excitation. Doubling the  $Er^{3+}$ concentration from 5% to 10% showed significant enhancement on the luminescence intensity for both the green and red emission bands. This increase in emission intensity is a result of ET between  $Er^{3+}$  ions in close proximity. When doped with 20%  $Er^{3+}$ , the intensity of all emission bands decreased considerably as result of concentration quenching.



**3.2.3.2** Y<sub>2</sub>O<sub>2</sub>S:Yb<sup>3+</sup>, Er<sup>3+</sup> Phosphors



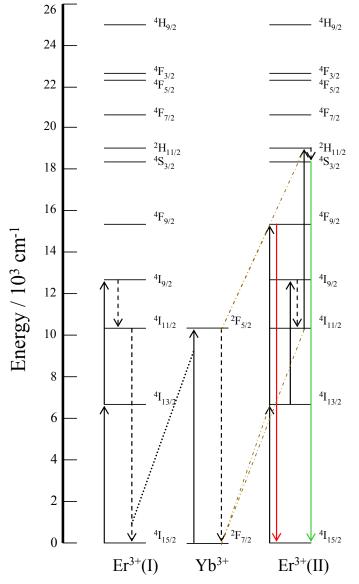
**Figure 21** UC emission spectra of  $Y_2O_2S$  phosphors co-doped with 20%  $Er^{3+}$  and X%  $Yb^{3+}$ , where X ranges from 0.0 - 5.0.

Figure 21 shows the room temperature UC emission spectra of  $Y_2O_2S$  phosphors doped with 20%  $Er^{3+}$ , X%  $Yb^{3+}$ , where X is incrementally increased by 2.5% from 0.0 -5.0 under 1560 nm excitation. Increasing the  $Yb^{3+}$  concentration in the fixed  $Er^{3+}$  doped phosphors from 0% to 5% caused the intensity of the red emission band corresponding to  ${}^{4}F_{9/2} \rightarrow {}^{4}I_{15/2}$  transition to increase significantly whereas the intensity of the green emission consistent with the  $({}^{2}H_{11/2}){}^{4}S_{3/2} \rightarrow {}^{4}I_{15/2}$  transition was only slightly enhanced.



Therefore, co-doping  $Er^{3+}$  with  $Yb^{3+}$  has a direct effect on the  ${}^{4}F_{9/2}$  emitting state. Two different mechanisms believed to be the most plausible are proposed, schematically shown, and addressed in detail.

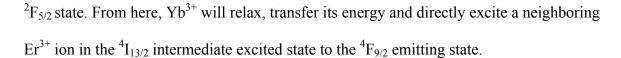


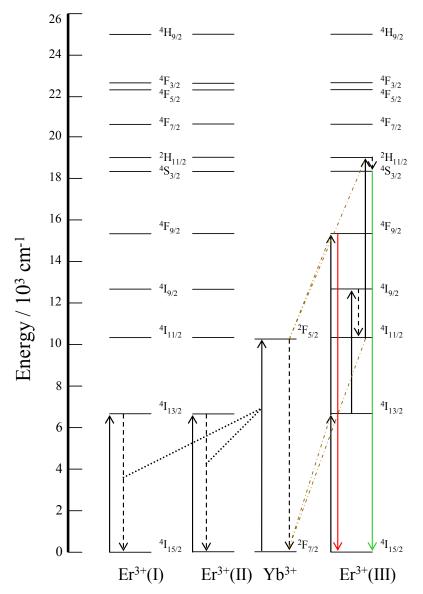


**Figure 22** Schematic: (1)  ${}^{4}I_{11/2}Er^{3+}(I) + {}^{2}F_{7/2}Yb^{3+} \rightarrow {}^{4}I_{15/2}Er^{3+}(I) + {}^{2}F_{5/2}Yb^{3+}$ (2)  ${}^{2}F_{5/2}Yb^{3+} + {}^{4}F_{13/2}Er^{3+}(II) \rightarrow {}^{2}F_{7/2}Yb^{3+} + {}^{4}F_{9/2}Er^{3+}(II)$  ET process possibly responsible for the  ${}^{4}F_{9/2}$  state under 1560 nm excitation.

In the first case (Figure 22), after a two-step ET process from neighboring  $\text{Er}^{3+}$ ions, non-radiative relaxation from the  ${}^{4}\text{I}_{11/2} \rightarrow {}^{4}\text{I}_{15/2}$  transition directly excites Yb<sup>3+</sup> to the







**Figure 23** Schematic: (1)  ${}^{4}I_{13/2}[Er^{3+}(I), (II), (III)] + {}^{2}F_{7/2}Yb^{3+} \rightarrow {}^{4}I_{15/2}[Er^{3+}(I), (II)] + {}^{2}F_{5/2}Yb^{3+}$ (2)  ${}^{2}F_{5/2}Yb^{3+} + {}^{4}I_{13/2}Er^{3+}(III) \rightarrow {}^{2}F_{7/2}Yb^{3+} + {}^{4}F_{9/2}Er^{3+}(III)$  cooperative sensitization ET process possibly responsible for the  ${}^{4}F_{9/2}$  state under 1560 nm excitation.



In the second case (Figure 23) known as cooperative sensitization ET, two individual  $Er^{3+}$  ions undergo GSA upon 1560 nm excitation exciting both of them into the  ${}^{4}I_{13/2}$  state. Simultaneous non-radiative relaxation back to the  ${}^{4}I_{15/2}$  ground state will directly excite a neighboring Yb<sup>3+</sup> ion to the  ${}^{2}F_{5/2}$  excited state where the energy that is being transferred by the cooperative sensitization process is at an energy resonant with the sum of the two excitation energies overlaps well with  ${}^{4}I_{5/2} \leftarrow {}^{4}I_{7/2}$  absorption band of Yb<sup>3+</sup>. Immediately following GSA of 1560 nm photon by a neighboring  $Er^{3+}$  ion, Yb<sup>3+</sup> will then relax and transfer its energy to the same neighboring  $Er^{3+}$  ion resulting in direct population of the  ${}^{4}F_{9/2}$  emitting state.

Rather than the usual consecutive three-photon excitation process that occurs from  $\text{Er}^{3+}$  only, the incorporation of  $\text{Yb}^{3+}$  creates a second, more efficient pathway for populating the  ${}^{4}\text{F}_{9/2}$  red emitting state. It is noteworthy to mention that the intensity of the red emission in a 20%  $\text{Er}^{3+}$  doped sample that earlier exhibited concentration quenching (Figure 21) was significantly enhanced by co-doping with  $\text{Yb}^{3+}$ .

Unfortunately, the power dependence measurements utilizing 1560 nm excitation will not be reported since this wavelength extends beyond the wavelength range of the power meter which is 1100 nm.



#### **3.3 Conclusions**

In conclusion, bulk  $Y_2O_2S$  phosphors, doped with  $Er^{3+}$  and co-doped with  $Yb^{3+}$ and  $Er^{3+}$ , were successfully prepared in high purity using the solid-state polysulfide flux method. The morphology and structure characterized using TEM showed that the asprepared oxysulfide phosphors clearly exhibited a spherical morphology with the exception of a few irregular hexagonal facet pieces. A rather large particle size distribution ranging from 2 - 5 µm was also observed. The crystallite size was determined to be approximately 35 nm using the Scherer equation and it is concluded that the irregular morphology and large distribution of particle sizes observed from the TEM micrographs is attributed to the aggregation of crystallites during the calcination process which had agglomeration to form the larger spherical particles. The XRD diffraction pattern consisted primarily of the  $Y_2O_2S$  phase and no evidence of  $Y_2O_3$  or fluxing agents was observed indicating that the sulfurization process of  $Y_2O_3$  was complete. Also, the absence of  $Yb_2O_2S$  and  $Er_2O_2S$  diffraction peaks suggested that the  $Yb^{3+}$  and  $Er^{3+}$  ions are well dispersed throughout the  $Y_2O_2S$  lattice.

Regardless of the excitation wavelength used, the UC emission spectra obtained for all samples possessed the same spectral profile and was independent of the Yb<sup>3+</sup> and  $Er^{3+}$  dopants as well as their respected concentrations. The green and red emissions occurring near 530 and 550 nm and 660 - 670 nm were consistent with the  $({}^{2}H_{11/2}){}^{4}S_{3/2} \rightarrow$  ${}^{4}I_{15/2}$  and  ${}^{4}F_{9/2} \rightarrow {}^{4}I_{15/2}$  transitions, respectively. The UC mechanisms excited at 808, 980, and 1560 nm were thoroughly discussed and investigated in detail. Monitoring the 547



and 670 nm emission peaks under both 808 and 980 nm excitation, the power dependent behavior on the UC emission intensities for singly doped  $\text{Er}^{3+}$  Y<sub>2</sub>O<sub>2</sub>S phosphors indicated that a two-photon excitation process was required for populating the <sup>4</sup>S<sub>3/2</sub> and <sup>4</sup>F<sub>9/2</sub> emitting states. Likewise, the Yb<sup>3+</sup> and Er<sup>3+</sup> co-doped phosphors excited at 980 nm also indicated a two-photon excitation process.

 $Y_2O_2S$  doped with 10%  $Er^{3+}$  showed the most intense UC emissions under 808 and 1560 nm excitation.  $Y_2O_2S$  co-doped with 15%  $Yb^{3+}$  and 3%  $Er^{3+}$  showed the most intense emissions under 980 nm excitation. Co-doping higher  $Er^{3+}$  concentrations in the 5%  $Yb^{3+}Y_2O_2S$  phosphors lead to a significant increase in the intensity of the red emission band accompanied by a decrease in the intensity of the green emission band. The observable changes in the intensity of the green and red emission bands were attributed to the non-radiative  ${}^4F_{7/2} \rightarrow {}^4F_{9/2}$  and  ${}^4I_{13/2} \rightarrow {}^4I_{15/2}$  transitions which became more predominant as the concentration of  $Er^{3+}$  reached nearly that of  $Yb^{3+}$ . Upon 1560 nm excitation, the intensity of the red emission band was significantly enhanced by codoping  $Er^{3+}$  with  $Yb^{3+}$ . Two different ET mechanisms believed to be the most plausible were proposed, schematically shown, and addressed in detail. The effects of concentration quenching became apparent when either the concentration of erbium or ytterbium reached 20%, respectively.



#### References

- <sup>[1]</sup> Wei, Y.; Lu, F.; Zhang, X.; Chen, D., *Journal of Alloys and Compounds*, 427, **2006** 333-340
- <sup>[2]</sup>Liu, Z, Sun, X.; Xu, S.; Lian, J.; Li, X,; Xiu, Z.; Li, Q.; Huo, D.; Li, J., *J. Phys. Chem.*
- C, 112, **2008**, 2353-2358
- <sup>[3]</sup> Vertone, F.; Boyer, J.; Speghini, A.; Bettinelli, M.; Capobianco, J., *J. App. Physics*, 96, 2004, 661-667
- <sup>[4]</sup> Vertone, F.; Boyer, J.; Capobianco, J.; Speghini, A.; Bettinelli, M., *Chem. Mater.*, 15, 2003, 2737-2743
- <sup>[5]</sup> Glaspell, G.; Anderson, J.; Wilkins, J.R.; El-Shall, M.S., *J. Phys. Chem. C*, 112, **2008**, 11527-11531
- <sup>[6]</sup> Silver, J.; Martinez-Rubio, M.; Ireland, T.; Fern, G.; Whitnall, R., *J. Phys. Chem. B*, 105, **2001**, 948-953
- <sup>[7]</sup> Xiao, S.; Yang, X.; Liu, Z.; Yan, X.H., J. App. Physics, 96, 2004 1360-1364
- <sup>[8]</sup> XiXian, L.; WangHe, C., Sci. Ser B-Chem, 50, 2007, 505-513
- <sup>[9]</sup> Yi, Guang-Shun; Chow, Gan-Moog., J. Mater. Chem., 15, 2005, 4460-4464
- <sup>[10]</sup> Yang, X.; Xiao, S.; Jing, J.W.; Yan, X.H., J. Mater. Sci., Vol. 42, 2007, 7042-7045
- <sup>[11]</sup> Wang, Y.; Ohwaki, J., J. App. Physics, Vol. 74, 1993 1272-1278



- <sup>[12]</sup> Mahalingam, V.; Mangiarini, F.; Vetrone, F.; Venkatramu, V.; Bettinelli, M.;
- Speghini, A.; Capobianco, J., J. Phys. Chem. C Letters, 112, 2008, 17745-17749
- <sup>[13]</sup> Rakov, N.; Guimaraes, R.B.; Maciel, G.S.; Appl. Phys. B, 98, 2010, 435-438
- <sup>[14]</sup> Vertone, F.; Boyer, J.; Capobianco, J.; Speghini, A.; Bettinelli, M., *J. Phys. Chem. B*, 107, **2003**, 1107-1112
- <sup>[15]</sup> Prasad, P.N., *Nanophotonics*; John Wiley and Sons: New York, 2004
- <sup>[16]</sup> Kuisheng, Y.; Yan, L.; Chaoyi, Y.; Liping, L.; Chanhua, Y.; Xiyan, Z., *J. Rare Earths*, 24, **2006**, 757-760
- <sup>[17]</sup> Luo, Xi-xian; Cao, Wang-he, *Materials Letters*, 61, **2007**, 3696-3700
- <sup>[18]</sup> Kawahara, Y.; Petrykin, V.; Ichihara, T.; Kijima, N.; Kakihana, M., *Chem. Mater.*, 18, **2006**, 6303-6307
- <sup>[19]</sup> Bang, J.; Abboudi, M.; Abrams, B.; Holloway, P.H., *J. Luminescence*, 106, **2004**, 177-185
- [<sup>20]</sup> Hang, T.; Liu, Q.; Mao, D.; Chang, C., *Materials Chemistry and Physics*, 107, **2008**, 142-147
- <sup>[21]</sup> Kuang, J.; Liu, Y.; Yuan, D., *Electrochemical and Solid-State Letters*, 8, **2005**, H72-
- H74
- <sup>[22]</sup> Lo, Chung-Lun.; Duh, Jeng-Gong.; Chiou, Bi-Shiou.; Peng, Chao-Chi.; Ozawa, L., *Materials Chemistry and Physics*, 71, **2001**, 179-189
- <sup>[23]</sup> Kottaisamy, M.; Jagannathan, R.; Rao, R.P.; Avudaithai, M.; Srinivasan, L.K.;
  Sundaram, V., *J. Electrochem. Soc.*, 142, **1995**, 3205-3209



<sup>[24]</sup> Georgobiani, A.N.; Bogatyreva, A.A.; Ishchenko, V.M.; Manashirov, O.Ya.; Gutan,

- V.B.; Semendyaev, S.V., Inorganic Materials, Vol. 43, 2007, 1073-1079
- <sup>[25]</sup> Vertone, F.; Boyer, J.; Speghini, A.; Bettinelli, M.; Capobianco, J., *J. Phys. Chem. B*,
  107, **2003**, 10747-10752

